

View Online at <https://aerobasegroup.com/nsn/5961-01-584-6369>

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-2.3 gate to source voltage

Current Rating Per Characteristic:

10.00 milliamperes forward gate current

Power Rating Per Characteristic:

300.0 milliwatts collector power dissipation

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction

Product Name:

N-channel jfet circuit

Special Features:

Hermetically sealed; military option; over-voltage protection; high performance jfet; 400 g fs min (us)

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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